



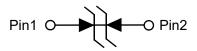
Bi-directional 18V Ultra Low Capacitance ESD Protector

Description

The PESDREC2XD18VBX is an ultra low capacitance ESD protection device specifically designed to protect high-speed lines. It protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one unidirectional line in applications where arrays are not practical.



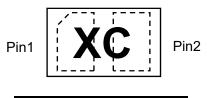
DFN0603-2L(Bottom View)



Circuit Diagram



- Ultra-Low capacitance: 0.15pF
- 45W peak pulse power per line (t_P = 8/20µs)
- DFN0603-2L package
- Response time is typically < 1 ns</p>
- Bidirectional configurations
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±15kV(air), ± 15kV(contact); IEC 61000-4-5 (Lightning) 6A (8/20us)



Marking (Top View)

Applications

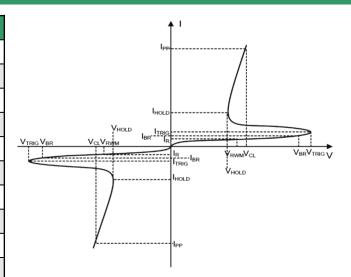
- > Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals

Mechanical Characteristics

- > Mounting position: Any
- Qualified max reflow temperature:260°C
- > Device meets MSL 1 requirements
- DFN0603-2L without plating

Electronics Parameter

Symbol	Parameter		
V _{RWM}	Reverse stand-off voltage		
I _R	Reverse leakage current		
V _{BR}	Reverse breakdown voltage		
I _{BR}	Reverse breakdown current		
V _{CL}	Clamping voltage		
V _{TRIG}	Reverse trigger voltage		
I _{TRIG}	Reverse trigger current		
V _{HOLD}	Reverse holding voltage		
I _{HOLD}	Reverse holding current		
I _{PP}	Peak pulse current		



Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V _{RWM}	-	-	-	18	V
Breakdown Voltage	V_{BR}	l _t = 1mA	19	23.6	26	V
Reverse Leakage Current	I _R	V _{RWM} = 18V	-	-	1	μA
Clamping Voltage	V _c	I _{PP} = 1A,t _P = 8/20µs	-	2.5	4.0	V
		I _{PP} = 6A,t _P = 8/20µs	-	6.0	9.0	
Dynamic resistance ¹⁾	R _{DYN}	-	-	0.25	-	Ω
Junction Capacitance	CJ	$V_R = 0V, f = 1MHz$	-	0.15	0.2	pF

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power (t _P = 8/20µs)	P _{PP}	45	W
Peak Pulse Current (t _P = 8/20µs)	I _{PP}	6.0	А
Lead Soldering Temperature	TL	260 (10 sec)	°C
Junction and Storage Temperature Range	T _{J,} T _{STG}	-55~+150	°C
ESD Protection-Contact Discharge	V _{ESD}	±15	kV
ESD Protection-Air Discharge	V _{ESD}	±15	kV

PESDREC2XD18VBX

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Typical Characteristics

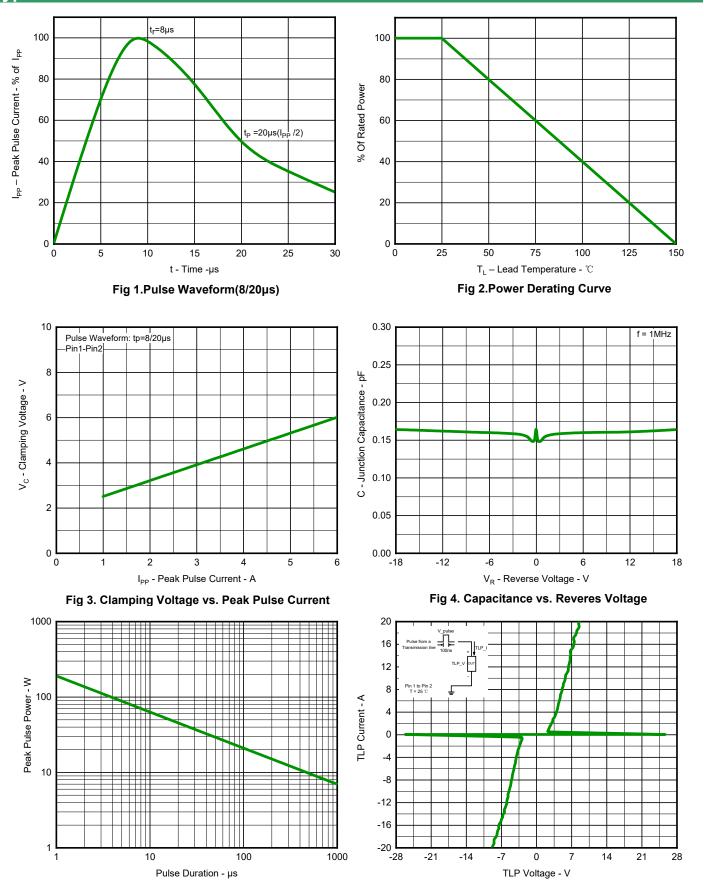
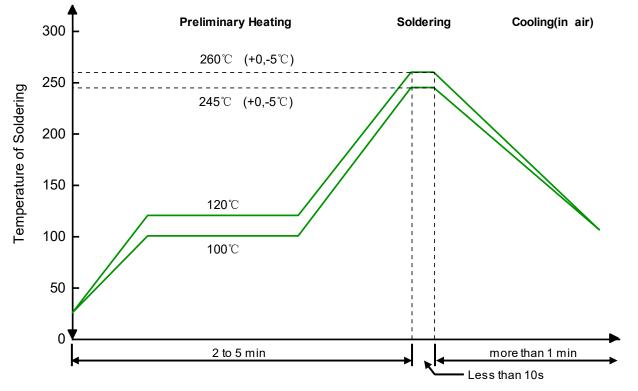


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse Time

Fig 6. TLP Measurement

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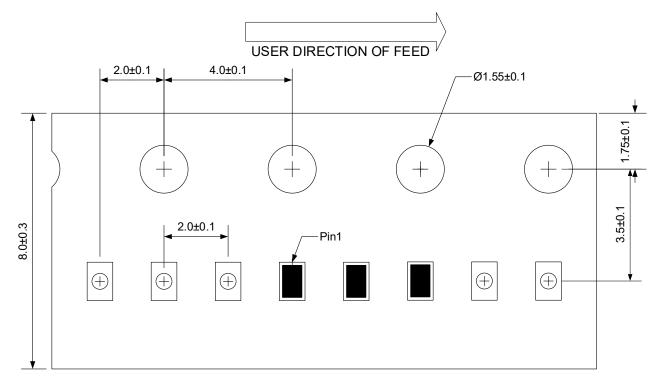
Solder Reflow Recommendation



Remark: Pb free for 260°C; Pb for 245°C.

PESDREC2XD18VBX

Load with information



Unit:mm

Ordering information

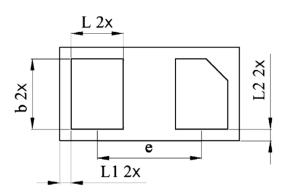
Device	Package	Reel	Shipping	
PESDREC2XD18VBX DFN0603-2L		7"	10000 / Tape & Reel	

PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

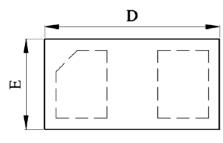
- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- > Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

Product dimension (DFN0603-2L)

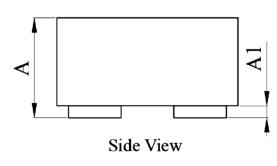


Bottom View

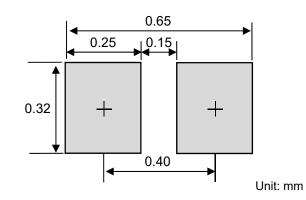
PESDREC2XD18VBX



Top View



Dim	Millimeters		Inches		
	Min	Max	Min	Max	
А	0.28	0.34	0.011	0.013	
A1	0.00	0.05	0.000	0.002	
b	0.215	0.265	0.008	0.010	
D	0.59	0.64	0.023	0.025	
E	0.29	0.34	0.011	0.013	
е	0.36 BSC		0.014 BSC		
L	0.155	0.205	0.006	0.008	
L1	0.040 BSC		0.002 BSC		
L2	0.040 BSC		0.002 BSC		



Suggested PCB Layout

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